

Amendments to the Claims

1. (canceled)

2. (canceled)

3. (currently amended) The A method of reducing differential-heating signal errors along a differential signal path claim-2, the method comprising the steps of:

coupling first and second transistors to different sides of said differential signal path; and

providing a differential correction signal to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;

further including the step of establishing respective bias parameters for at least one set of same terminals of said first and second transistors that differ from said like terminals;

wherein said first and second transistors are bipolar junction transistors, said like terminals are emitters, same terminals of one set are collectors and their respective bias parameter is current, and same terminals of another set are bases and their respective bias parameter is voltage.

4. (currently amended) The A method of reducing differential-heating signal errors along a differential signal path claim-2, the method comprising the steps of:

coupling first and second transistors to different sides of said differential signal path; and

providing a differential correction signal to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;

further including the step of establishing respective bias parameters for at least one set of same terminals of said first and second transistors that differ from said like terminals;

wherein said first and second transistors are metal-oxide semiconductor transistors, said like terminals are sources, same terminals of one set are drains and their respective bias parameter is current, and same terminals of another set are gates and their respective bias parameter is voltage.

5. (currently amended) The method of claim 31, wherein said providing step includes the step of amplifying said differential error signal to realize said differential correction signal.

6. (currently amended) The method of claim 31, wherein said differential correction signal is a differential current signal.

7. (currently amended) The method of claim 31, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is provided to the other of said upstream and downstream portions.

8. (currently amended) The method of claim 31, wherein said coupling step includes the step of directly connecting said first and second transistors to said different sides of said differential signal path.

9. (canceled)

10. (currently amended) The sensor of claim 119, further including a bias generator which biases at least one set of same terminals of said first and second transistors that differ from said like terminals.

11. (currently amended) The A correction sensor for reduction of differential-heating signal errors along a differential signal path of claim 10, the sensor comprising:

first and second transistors coupled to different sides of said differential signal path; and
a differential error amplifier that couples a differential correction signal

to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;

further including a bias generator which biases at least one set of same terminals of said first and second transistors that differ from said like terminals;

wherein:

said first and second transistors are bipolar junction transistors and said like terminals are emitters;

same terminals of one set are collectors and a respective bias generator is at least one current source; and

same terminals of another set are bases and a respective bias generator is a voltage source.

12. (currently amended) The A correction sensor for reduction of differential-heating signal errors along a differential signal path of claim 10, the sensor comprising:

first and second transistors coupled to different sides of said differential signal path; and

a differential error amplifier that couples a differential correction signal to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;

further including a bias generator which biases at least one set of same terminals of said first and second transistors that differ from said like terminals;

wherein:

said first and second transistors are metal-oxide semiconductor transistors and said like terminals are sources;

same terminals of one set are drains and a respective bias generator is at least one current source; and

same terminals of another set are gates and a respective bias generator is a voltage source.

13. (currently amended) The sensor of claim 119, wherein said differential error amplifier includes a differential pair of transistors and said differential correction signal is a differential current.

14. (currently amended) The sensor of claim 119, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is coupled to the other of said upstream and downstream portions.

15. (currently amended) The sensor of claim 119, wherein said first and second transistors are directly connected to said different sides of said differential signal path.

16. (canceled)

17. (currently amended) The amplifier of claim 1916, further including a bias generator that establishes respective bias parameters for at least one set of same terminals of said first and second transistors that differ from said like terminals.

18. (original) The amplifier of claim 17, wherein said bias generator comprises first and second current sources that couple first and second currents through said first and second transistors.

19. (currently amended) The ~~An~~ amplifier of claim ~~16~~, comprising:
a differential amplifier that processes a differential signal along a
differential signal path; and
a correction sensor that has first and second transistors coupled to
different sides of said differential signal path and a differential error
amplifier that couples a differential correction signal to said
differential signal path in differential response to a differential error
signal generated by like terminals of said first and second
transistors;

wherein said first and second transistors are bipolar junction transistors and said like terminals are emitters of said bipolar junction transistors;

differential-heating signal errors of said differential amplifier thereby reduced by said sensor.

20. (currently amended) ~~The~~ An amplifier of ~~claim 16~~, comprising:
a differential amplifier that processes a differential signal along a differential signal path; and
a correction sensor that has first and second transistors coupled to different sides of said differential signal path and a differential error amplifier that couples a differential correction signal to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;

wherein said first and second transistors are metal-oxide semiconductor transistors and said like terminals are sources of said metal-oxide semiconductor transistors;

differential-heating signal errors of said differential amplifier thereby reduced by said sensor.

21. (currently amended) The amplifier of claim 19~~16~~, wherein:
said differential amplifier includes a differential pair of transistors and first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals of said differential pair;
said first and second transistors are coupled to said buffer output terminals; and
said correction sensor is coupled to said buffer input terminals.

22. (currently amended) The amplifier of claim 19~~16~~, wherein:
said differential amplifier includes a differential pair of transistors and first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals

of said differential pair;
said first and second transistors are coupled to said buffer output terminals; and
said correction sensor is coupled to differential input terminals of said differential amplifier.

23. (currently amended) The amplifier of claim 1916, wherein:
said differential amplifier includes a differential pair of transistors and first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals of said differential pair;
said first and second transistors are coupled to said differential input terminals of said differential amplifier; and
said correction sensor is coupled to differential output terminals of said differential amplifier.

24. (currently amended) The amplifier of claim 1916, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is coupled to the other of said upstream and downstream portions.

25. (currently amended) The amplifier of claim 1916, wherein said first and second transistors are directly connected to said different sides of said differential signal path.

26. (currently amended) A pin electronics system for testing of a device-under-test (DUT) at a DUT system port, comprising:
a pin driver that applies an excitation signal to said system port;
an active load that provides a load to said system port; and
a comparator coupled to said system port to compare a response signal of said DUT to a predetermined reference signal;
wherein at least one of said pin driver, active load and comparator includes:
a) a differential pair of transistors positioned to process a differential

- signal along a differential signal path;
- b) first and second transistors coupled to different sides of said differential signal path; and
- c) a differential error amplifier that couples a differential correction signal to said differential signal path in differential response to a differential error signal generated by like terminals of said first and second transistors;
- differential-heating signal errors of said differential pair thereby reduced by said sensor.

27. (original) The system of claim 26, further including a bias generator that establishes respective bias parameters for at least one set of same terminals of said first and second transistors that differ from said like terminals.

28. (original) The system of claim 26, wherein said first and second transistors are bipolar junction transistors and said like terminals are emitters of said bipolar junction transistors.

29. (original) The system of claim 26, wherein said first and second transistors are metal-oxide semiconductor transistors and said like terminals are sources of said metal-oxide semiconductor transistors.

30. (original) The system of claim 26, wherein:
said differential amplifier includes a differential pair of transistors and first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals of said differential pair;
said first and second transistors are coupled to said buffer output terminals; and
said correction sensor is coupled to said buffer input terminals.

31. (original) The system of claim 26, wherein:
said differential amplifier includes a differential pair of transistors and

first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals of said differential pair;
said first and second transistors are coupled to said buffer output terminals; and
said correction sensor is coupled to differential input terminals of said differential amplifier.

32. (original) The system of claim 26, wherein:

said differential amplifier includes a differential pair of transistors and first and second buffers that have buffer output terminals and also have buffer input terminals coupled to differential output terminals of said differential pair;
said first and second transistors are coupled to said differential input terminals of said differential amplifier; and
said correction sensor is coupled to differential output terminals of said differential amplifier.

33. (original) The system of claim 26, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is coupled to the other of said upstream and downstream portions.

34. (original) The amplifier of claim 26, wherein said first and second transistors are directly connected to said different sides of said differential signal path.

35. (added) The method of claim 4, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is provided to the other of said upstream and downstream portions.

36. (added) The sensor of claim 12, wherein said first and second transistors are coupled to one of upstream and downstream portions of said

differential signal path and said differential correction signal is coupled to the other of said upstream and downstream portions.

37. (added) The amplifier of claim 20, wherein said first and second transistors are coupled to one of upstream and downstream portions of said differential signal path and said differential correction signal is coupled to the other of said upstream and downstream portions.